UNITED STATES PATENT AND TRADEMARK OFFICE **CERTIFICATE OF CORRECTION**

PATENT NO.

: 7,547,909 B2

APPLICATION NO.: 10/597607

DATED

: June 16, 2009

INVENTOR(S)

: Joongseo Park

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title lage, Item (54) and Column 1, lines 1-3

Please delete "III_NITRIDE COMPOUND ICE SEMICONDUCTOR LIGHT EMITTING DEV" and insert -- III-NITRIDE COMPOUND SEMICONDUCTOR LIGHT EMITTING DEVICE-

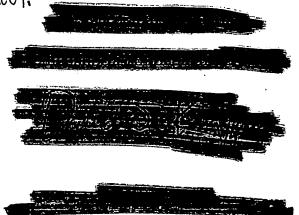
Title lage, Item (22)

Please delete "March 5, 2005" and insert -February 5, 2005-

Title Page, Item (86)

For the filing or '371c' date, delete "August 1, 2006" and insert -- August 3, 2006--

This certificate supersedes certificate of correction issued September 15, 2009.



Page 1 of 1

Note

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